

**FEATURES:**

- Glass Passivated Chip Junction
- Reverse Voltage - 100 to 1000 V
- Average Rectified Output Current- 0.6 A
- High Surge Current Capability
- Designed for Surface Mount Application

**VOLTAGE RANGE**

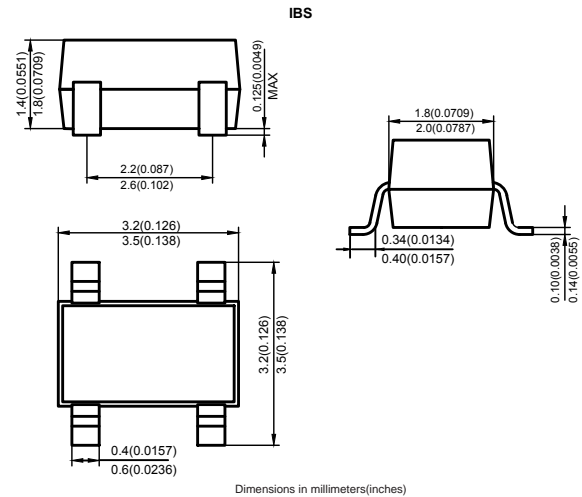
50 to 1000 Volts

**CURRENT**

0.6 Ampere

**MECHANICAL DATA**

- Case: I B S
- Terminals: Solderable per MIL-STD-750, Method 2026



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.  
 Single phase half wave, 60Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

TYPE NUMBER	IB05S	IB1S	IB2S	IB4S	IB6S	IB8S	IB10S	UNIT	
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V	
Maximum RMS Voltage	35	70	140	280	420	560	700	V	
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V	
Maximum Average Forward Rectified Current at Ta=40°C(Note 1)								0.6	A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)								25	A
I <sup>2</sup> t Rating for Fusing (1ms < t < 8.3ms)								2.59	A <sup>2</sup> S
Maximum Forward Voltage Drop per Bridge Element at 0.3A D.C.								1.0	V
Maximum DC Reverse Current at Rated DC Blocking Voltage								5.0	µA
Typical Thermal Resistance R <sub>JA</sub> (Note 2)								60	°C/W
Operating Temperature Range, T <sub>J</sub>								-55 — +150	°C
Storage Temperature Range, T <sub>STG</sub>								-55 — +150	°C

NOTES: 1. Mounted on P.C. Board.  
 2. Thermal Resistance Junction to Ambient.

## RATING AND CHARACTERISTIC CURVES (IB05S THRU IB10S)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

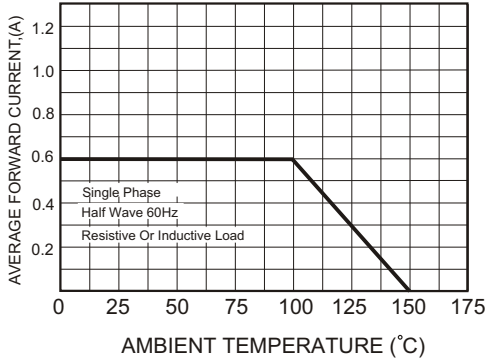


FIG.2-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

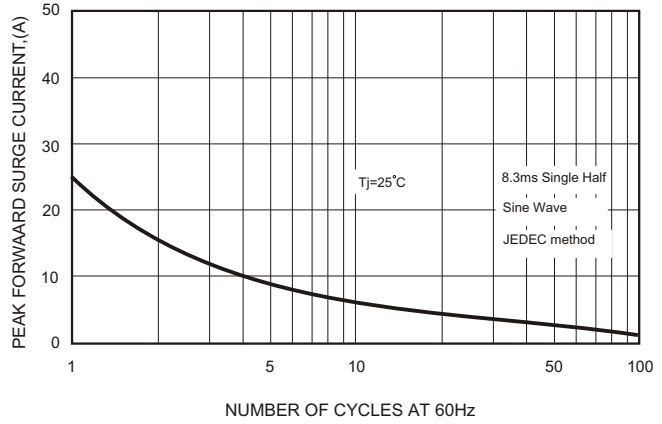


FIG.3-TYPICAL FORWARD CHARACTERISTICS

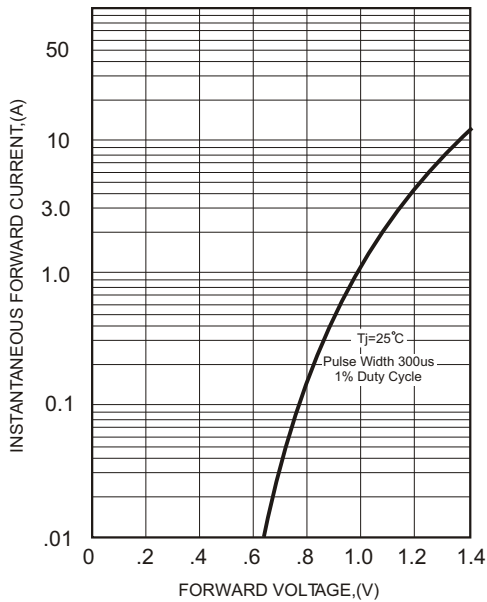


FIG.4-TYPICAL REVERSE CHARACTERISTICS

